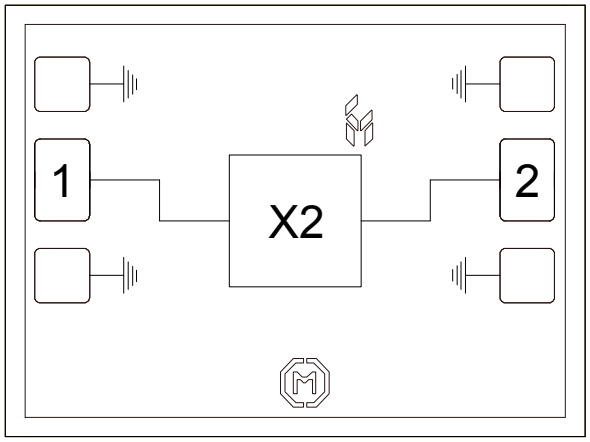
CMD225

Passive Frequency Doubler, 4-8 GHz Input

Features

- Low conversion loss
- Excellent Fo isolation
- Broadband performance
- No bias required
- Small die size

Functional Block Diagram



Description

The CMD225 die is a broadband MMIC GaAs x2 passive frequency multiplier. When driven by a +15 dBm signal, the multiplier provides 12 dB conversion loss at an output frequency of 12 GHz. The Fo and 3Fo isolations are >48 dBc and >51 dBc respectively. The CMD225 is a 50 ohm matched design eliminating the need for external DC blocks and RF port matching.

Electrical Performance - T_A = 25 °C, Pin = +15 dBm, Fin = 6 GHz

Parameter	Min	Typ	Max	Units
Frequency Range, Input		4 - 8		GHz
Frequency Range, Output		8 - 16		GHz
Conversion Loss		12		dB
Fo Isolation (with respect to input level)		48		dB
3Fo Isolation (with respect to input level)		50		dB
4Fo Isolation (with respect to input level)		50		dB

Custom MMIC
300 Apollo Drive Chelmsford, MA 01824 Phone (978) 467-4290 Fax (978) 467-4294
Visit us online at www.custommmic.com

Specifications

Absolute Maximum Ratings

Parameter	Rating
RF Input Power	+27 dBm
Operating Temperature	-55 to 85 °C
Storage Temperature	-55 to 150 °C

Operation of this device outside the maximum ratings may cause permanent damage.

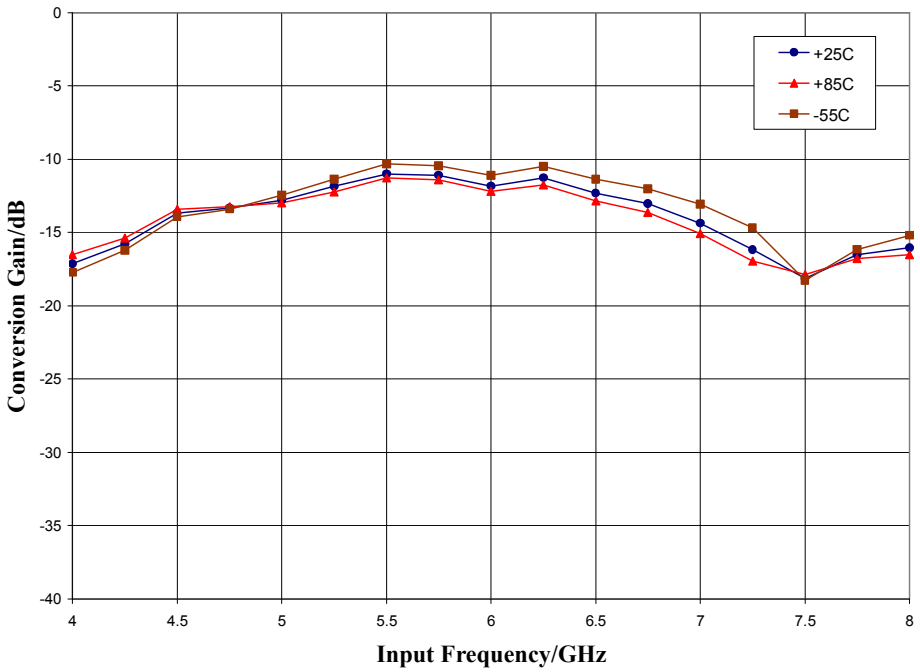
Electrical Specifications - T_A = 25 °C, Pin = +15 dBm

Parameter	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range, Input	4 - 8			5 - 7			GHz
Frequency Range, Output	8 - 16			10 - 14			GHz
Conversion Loss		12	19		12	16	dB
Fo Isolation (with respect to input level)	33	48		38	48		dB
3Fo Isolation (with respect to input level)	43	50		43	50		dB
4Fo Isolation (with respect to input level)	23	50		33	50		dB

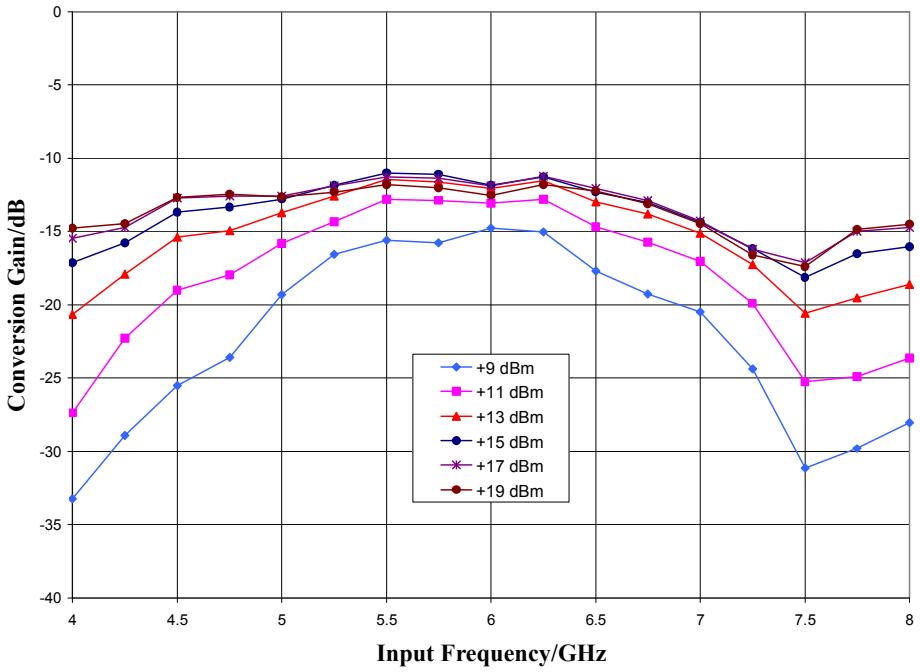
Custom MMIC
300 Apollo Drive Chelmsford, MA 01824 Phone (978) 467-4290 Fax (978) 467-4294
Visit us online at www.custommmic.com

Typical Performance

Conversion Gain vs. Temperature @ +15 dBm Drive Level



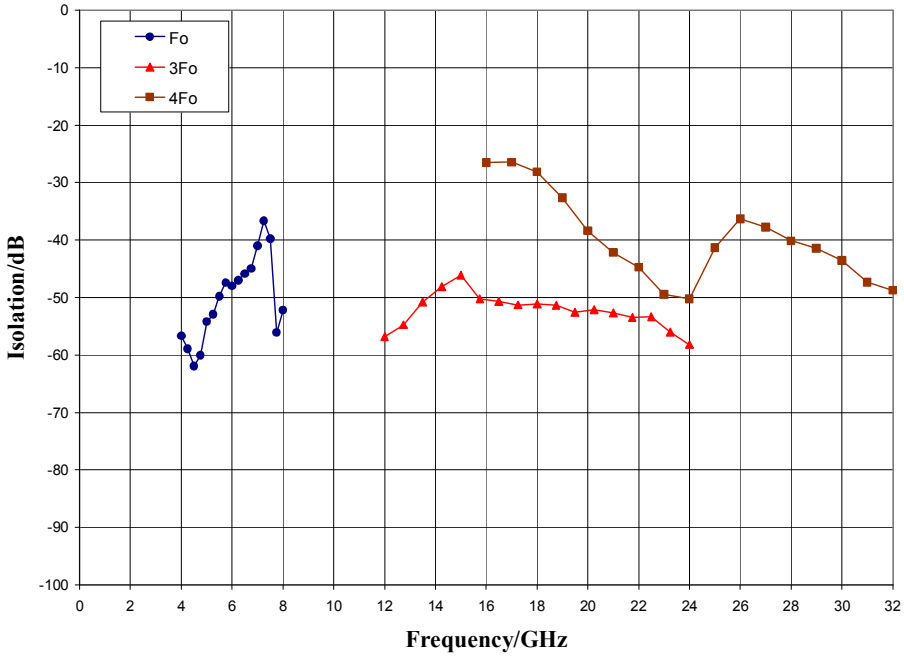
Conversion Gain vs. Drive Level, T_A = 25 °C



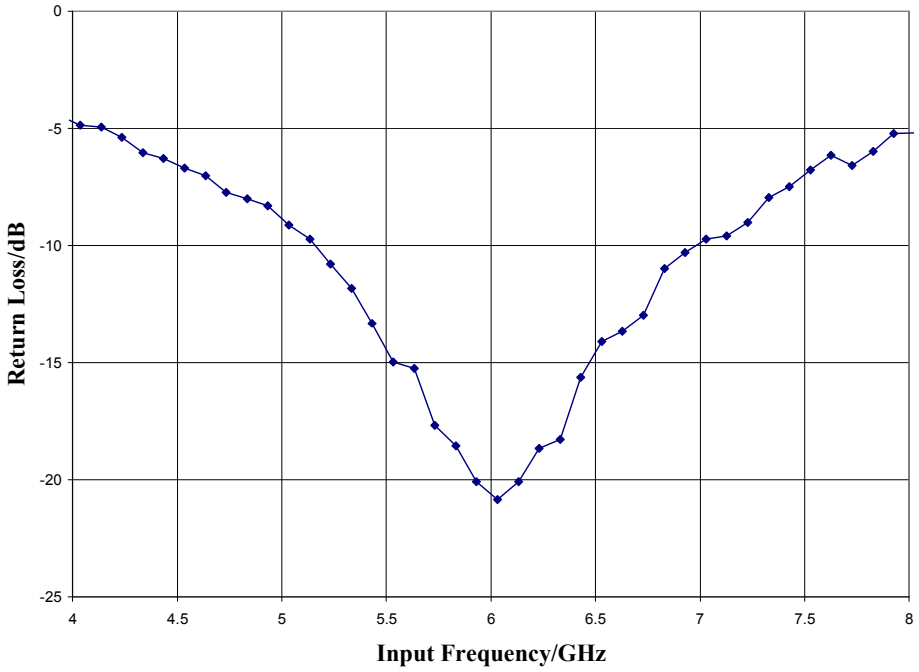
Custom MMIC
300 Apollo Drive Chelmsford, MA 01824 Phone (978) 467-4290 Fax (978) 467-4294
Visit us online at www.custommmic.com

Typical Performance

Isolation (with respect to input level) @ +15 dBm Drive Level, T_A = 25 °C



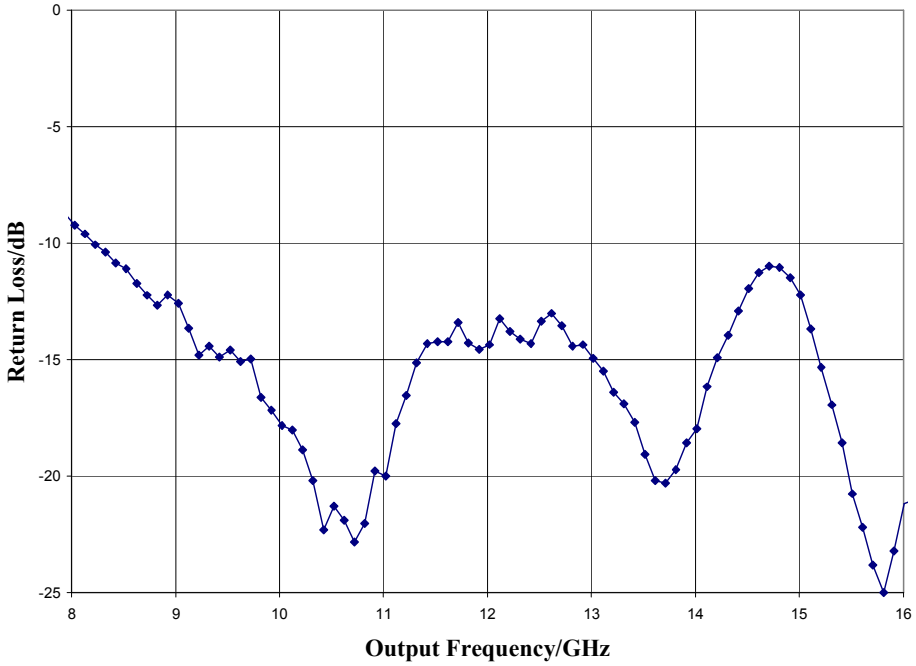
Input Return Loss @ +15 dBm Drive Level, T_A = 25 °C



Custom MMIC
300 Apollo Drive Chelmsford, MA 01824 Phone (978) 467-4290 Fax (978) 467-4294
Visit us online at www.custommmic.com

Typical Performance

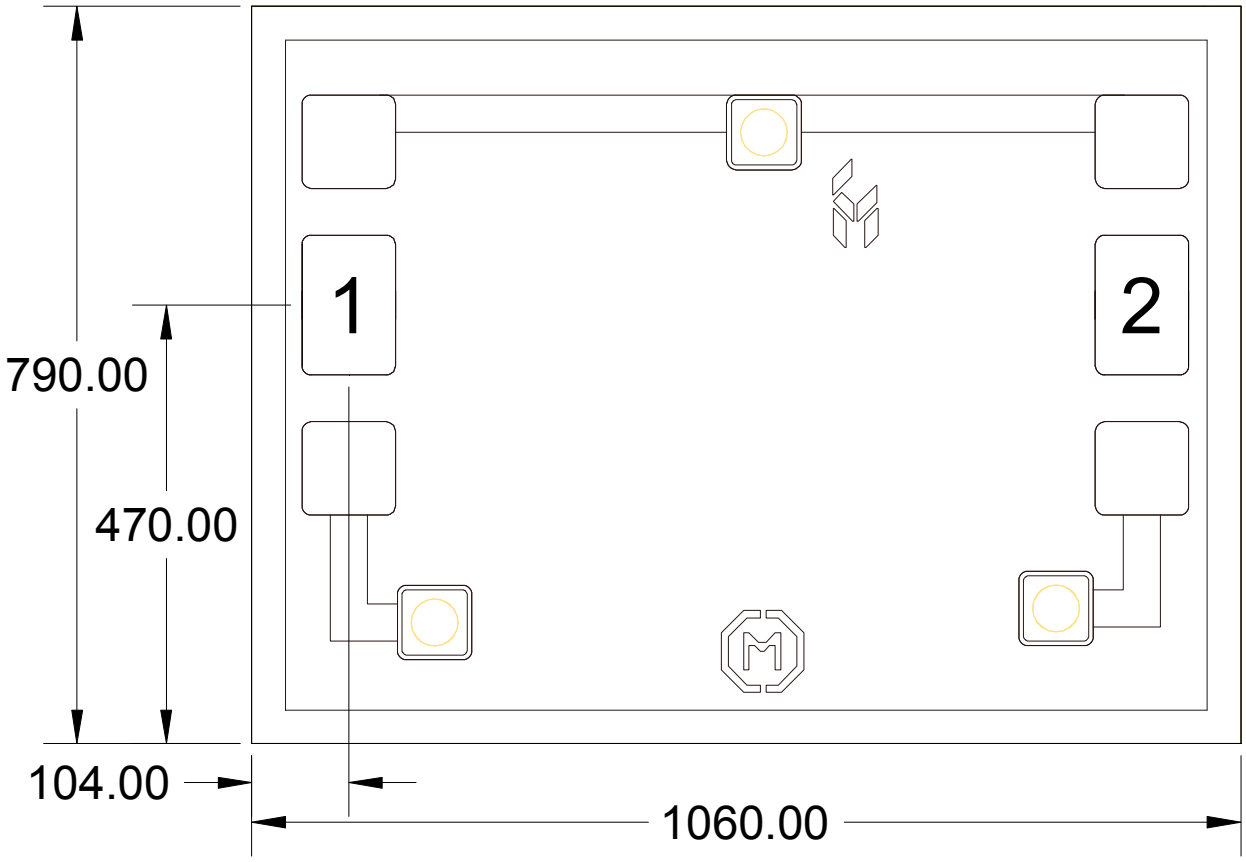
Output Return Loss @ +15 dBm Drive Level, F = 6 GHz Input, T_A = 25 °C



Custom MMIC
300 Apollo Drive Chelmsford, MA 01824 Phone (978) 467-4290 Fax (978) 467-4294
Visit us online at www.custommmic.com

Mechanical Information

Die Outline (all dimensions in microns)



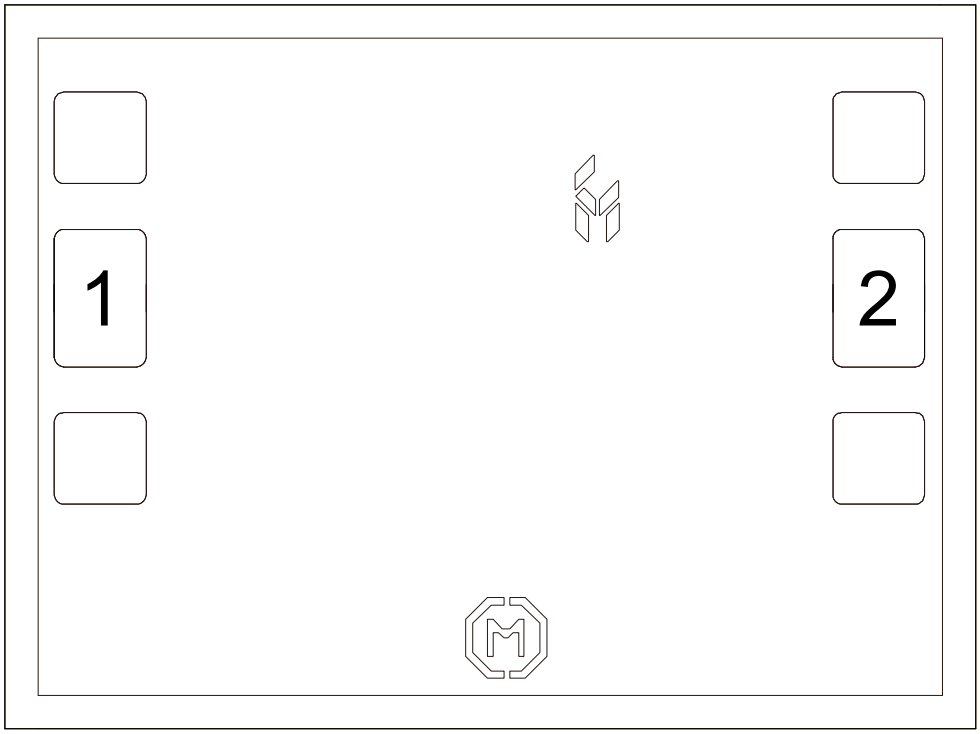
Notes:

1. No connection required for unlabeled pads
2. Backside is RF and DC ground
3. Backside and bond pad metal: Gold
4. Die is 100 microns thick
5. DC bond pads are 100 microns square

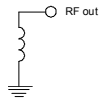
Custom MMIC
300 Apollo Drive Chelmsford, MA 01824 Phone (978) 467-4290 Fax (978) 467-4294
Visit us online at www.custommmic.com

Pin Description

Pad Diagram



Functional Description

Pad	Function	Description	Schematic
1	RF in	Pad is DC coupled and 50 ohm matched	
2	RF out	Pad is DC coupled and 50 ohm matched	
Backside	Ground	Connect to RF / DC ground	

Custom MMIC
300 Apollo Drive Chelmsford, MA 01824 Phone (978) 467-4290 Fax (978) 467-4294
Visit us online at www.custommmic.com

Applications Information

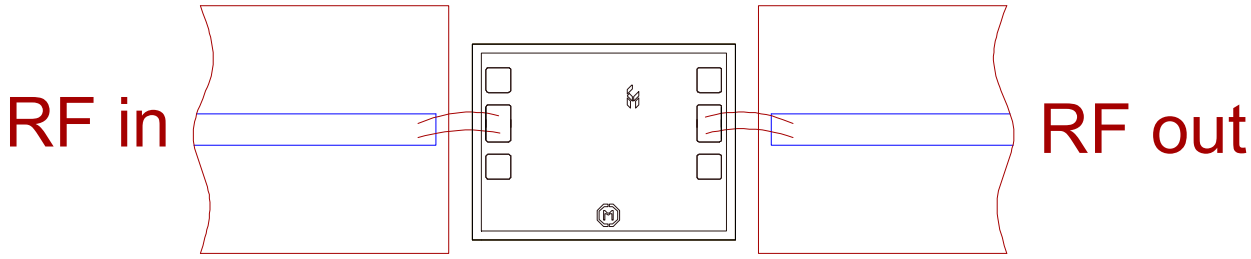
Assembly Guidelines

The backside of the CMD225 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy or eutectic attach. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized. The RF input and output require a single bond wire as shown.

The semiconductor is 100 um thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

Assembly Diagram



GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

Custom MMIC
300 Apollo Drive Chelmsford, MA 01824 Phone (978) 467-4290 Fax (978) 467-4294
Visit us online at www.custommmic.com